

YJ Planar Schottky Barrier Diode Die Specification

200V 200A, 250mil, Schottky barrier diode die based on silicon planar process
Part No.: PSB275H200AS-290A

Main Products Characteristics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 200 \text{ A}$

2%

Device Schematics and Outline Drawing

Die Thickness *